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## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



Enable High Flux and Cost Efficient System

## Z Power Chip on board – ZC series

**SDWx1F1C (SDW01F1C, SDW81F1C, SDW91F1C)**



## Product Brief

### Description

- The ZC series are LED arrays which provide High Flux and High Efficacy.
- It is especially designed for easy assembly of lighting fixtures by eliminating reflow soldering process.
- It's thermal management is better than other power LED solutions with wide Metal area.
- ZC series are ideal light sources for General Lighting applications including Replacement Lamps, Industrial & Commercial Lightings and other high Lumen required applications.

### Features and Benefits

- Size 13.5mm \* 13.5mm
- Power dissipation 6.3 ~ 18.4W
- Wide CCT range with CRI70~90
- Forward  $V_F$  34.8V
- Maximum Current 460mA
- MacAdam 3-step binning
- Uniformed Shadow
- Excellent Thermal management
- RoHS compliant

### Key Applications

- Commercial – Downlight
- Replacement lamps – Bulb, PAR, MR16
- Industrial
- Residential

**Table 1. Product Selection Table**

Part Number	CCT [K]			
	Color	Min.	Typ.	Max.
SDW01F1C	Cool White	4,700	-	6,000
	Neutral White	3,700	-	4,700
SDW81F1C	Cool White	4,700	-	6,000
	Neutral White	3,700	-	4,700
	Warm White	2,600	-	3,700
SDW91F1C	Neutral White	3,700	-	4,200
	Warm White	2,600	-	3,700

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## Product Performance & Characterization Guide

**Table 2. Electro Optical Characteristics,  $T_j=25^{\circ}\text{C}$** 

Part Number	CCT (K) <sup>[1]</sup>	Typical Luminous Flux <sup>[2]</sup> , $\Phi_v$ <sup>[3]</sup> (lm)		Typical Forward Voltage, $V_F$ <sup>[4]</sup> (V)		CRI <sup>[5]</sup> , $R_a$	Viewing Angle (degrees) $2\theta_{1/2}$
	Typ.	180mA	460mA*	180mA	460mA*	Min.	Typ.
SDW01F1C	5600	870	1,931	34.8	38.1	70	120
	5000	885	1,960	34.8	38.1	70	120
	4500	915	2,013	34.8	38.1	70	120
	4000	913	2,008	34.8	38.1	70	120
SDW81F1C	5600	815	1810	34.8	38.1	80	120
	5000	820	1820	34.8	38.1	80	120
	4500	790	1760	34.8	38.1	80	120
	4000	775	1661	34.8	38.1	80	120
	3500	757	1622	34.8	38.1	80	120
	3000	750	1608	34.8	38.1	80	120
	2700	720	1541	34.8	38.1	80	120
SDW94F1C	4000	680	1470	34.8	38.1	90	120
	3500	645	1393	34.8	38.1	90	120
	3000	635	1371	34.8	38.1	90	120
	2700	600	1294	34.8	38.1	90	120

**Notes :**

- (1) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram. Color coordinate :  $\pm 0.01$ , CCT  $\pm 5\%$  tolerance.
- (2) Seoul Semiconductor maintains a tolerance of  $\pm 7\%$  on flux and power measurements.
- (3)  $\Phi_v$  is the total luminous flux output as measured with an integrating sphere.
- (4) Tolerance is  $\pm 3\%$  on forward voltage measurements.
- (5) Tolerance is  $\pm 2$  on CRI measurements.

\* No values are provided by real measurement. Only for reference purpose.

## Product Performance & Characterization Guide

**Table 3. Electro Optical Characteristics,  $T_j=85^{\circ}\text{C}$** 

Part Number	CCT (K) <sup>[1]</sup>	Typical Luminous Flux <sup>[2]</sup> , $\Phi_v$ <sup>[3]</sup> (lm)	Typical Forward Voltage, $V_f$ <sup>[4]</sup> (V)
	Typ.	180mA *	180mA *
SDW01F1C	5600	783	33.3
	5000	797	33.3
	4500	824	33.3
	4000	822	33.3
SDW81F1C	5600	725	33.3
	5000	730	33.3
	4500	703	33.3
	4000	690	33.3
	3500	674	33.3
	3000	668	33.3
	2700	641	33.3
SDW91F1C	4000	592	33.3
	3500	561	33.3
	3000	552	33.3
	2700	522	33.3

**Notes :**

- (1) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram. Color coordinate :  $\pm 0.01$ , CCT  $\pm 5\%$  tolerance.
- (2) Seoul Semiconductor maintains a tolerance of  $\pm 7\%$  on flux and power measurements.
- (3)  $\Phi_v$  is the total luminous flux output as measured with an integrating sphere.
- (4) Tolerance is  $\pm 3\%$  on forward voltage measurements.
- (5) Tolerance is  $\pm 2$  on CRI measurements.

\* No values are provided by real measurement. Only for reference purpose.

## Product Performance & Characterization Guide

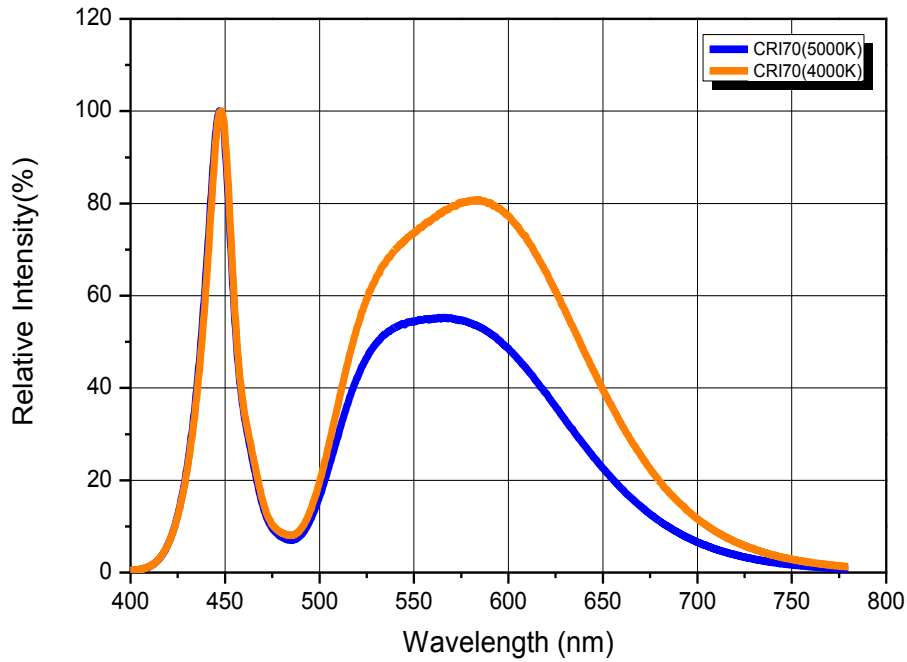
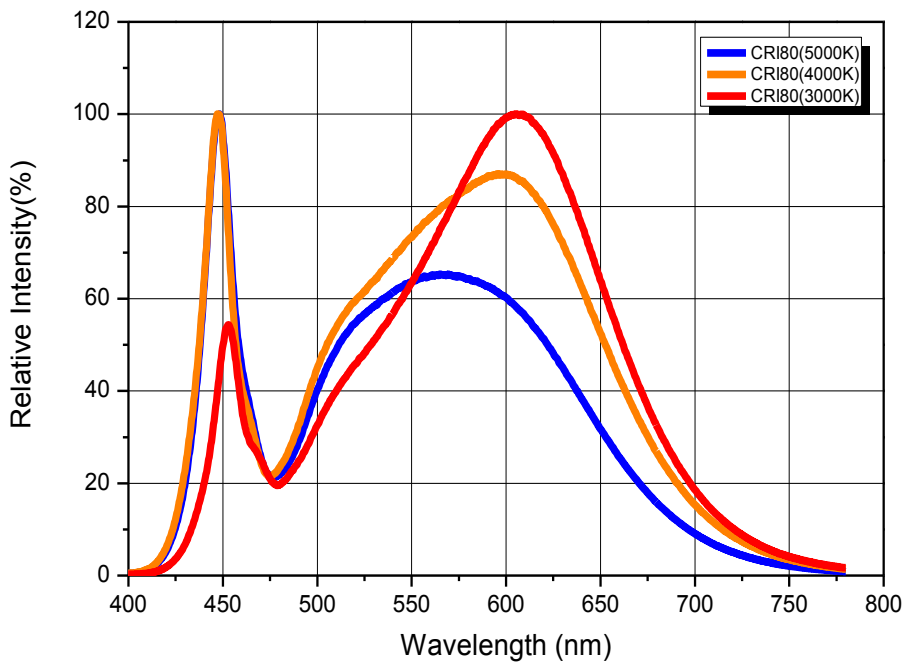
**Table 4. Absolute Maximum Characteristics,  $T_j=25^{\circ}\text{C}$** 

Parameter	Symbol	Value			Unit
		Min.	Typ.	Max.	
Forward Current	$I_F$	-	0.18	0.46	A
Power Dissipation	$P_d$	-	6.3	18.4	W
Junction Temperature	$T_j$	-	-	140	$^{\circ}\text{C}$
Operating Temperature	$T_{opr}$	-40	-	85	$^{\circ}\text{C}$
Surface Temperature	$T_s$	-	-	100	$^{\circ}\text{C}$
Storage Temperature	$T_{stg}$	-40	-	100	$^{\circ}\text{C}$
Thermal resistance (J to S) <sup>[1]</sup>	$R\theta_{J-S}$	-	1.68	-	K/W
ESD Sensitivity(HBM)	-	Class 3A JESD22-A114-E			

**Notes :**

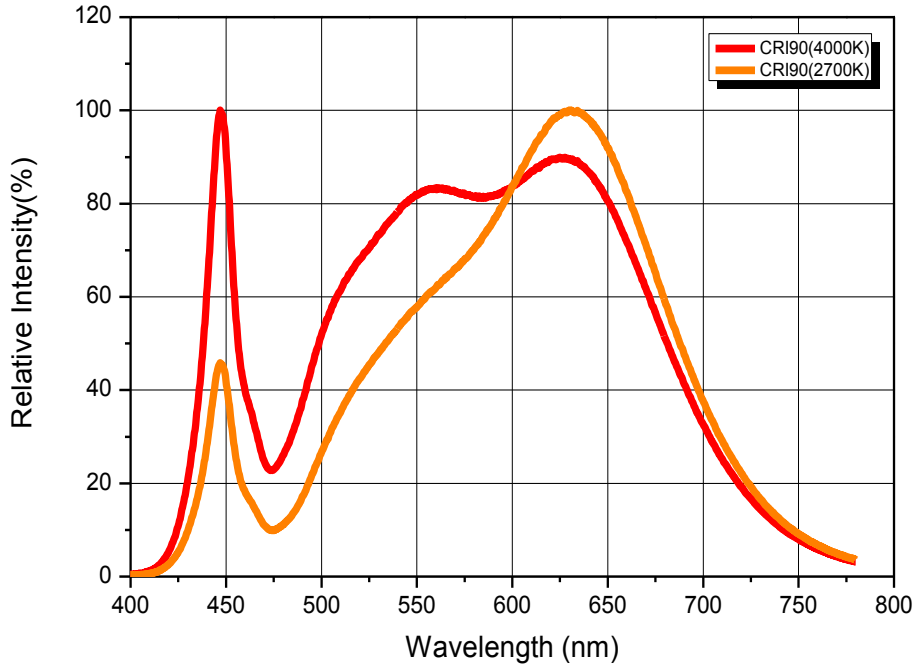
(1) Thermal Resistance :  $R\theta_{J-S}$  (Junction to  $T_s$  point)

## Characteristics Graph

**Fig 1. Color Spectrum,  $T_j=25^\circ\text{C}$ ,  $I_F=180\text{mA}$  (CRI70)**

**Fig 2. Color Spectrum,  $T_j=25^\circ\text{C}$ ,  $I_F=180\text{mA}$  (CRI80)**


## Characteristics Graph

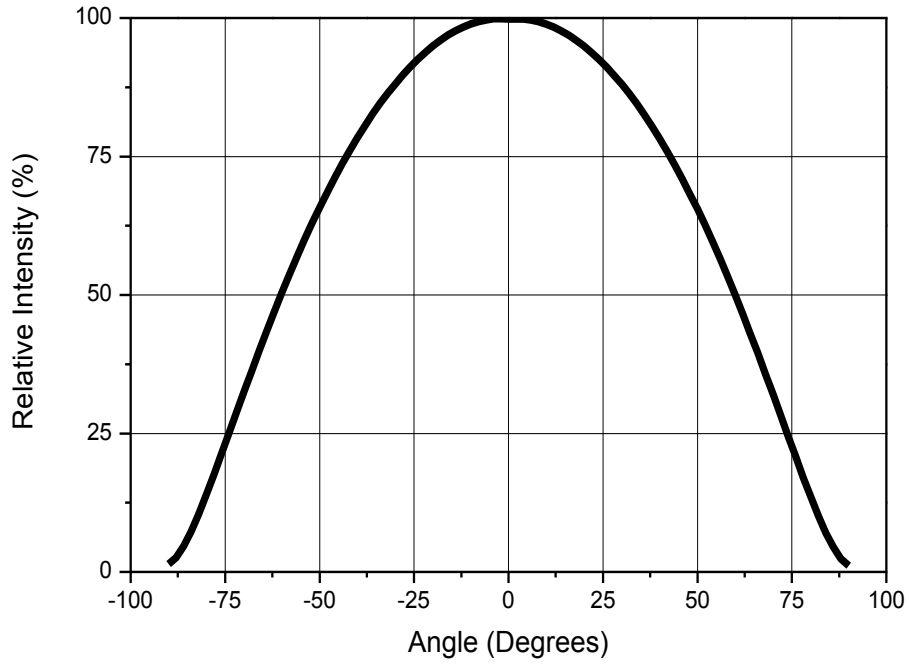
Fig 3. Color Spectrum,  $T_j=25^\circ\text{C}$ ,  $I_F=180\text{mA}$  (CRI90)



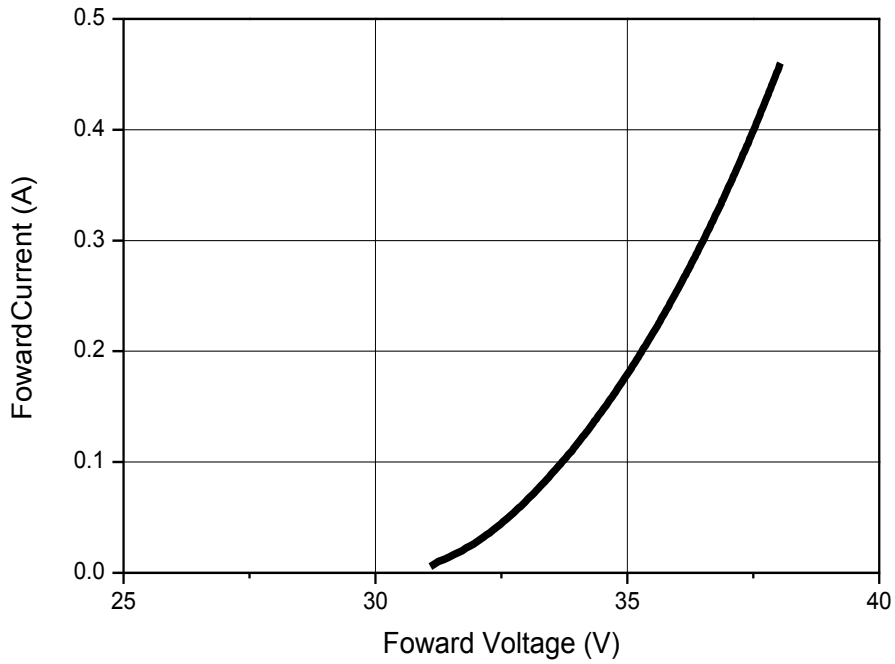
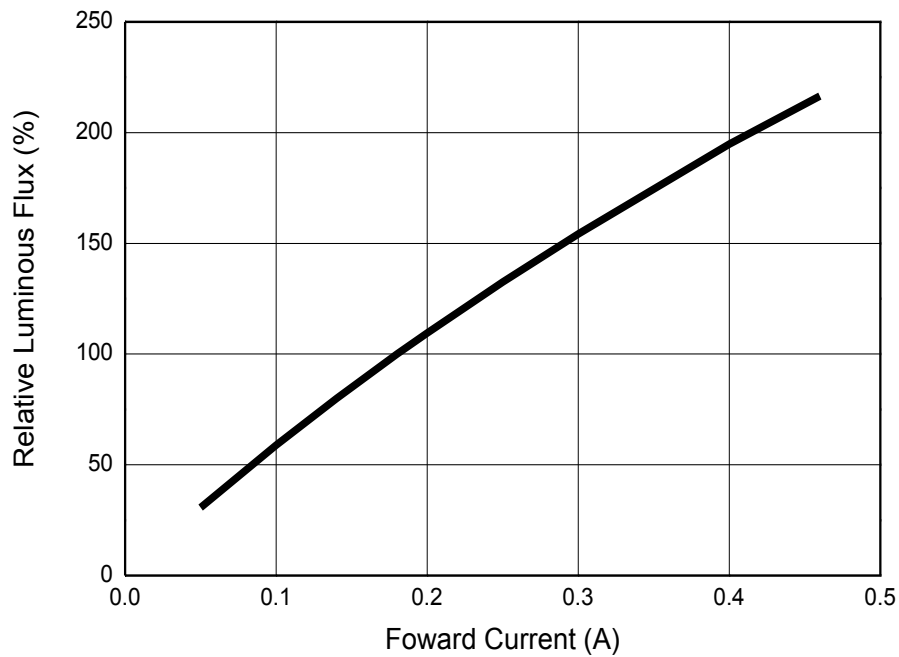


## Characteristics Graph

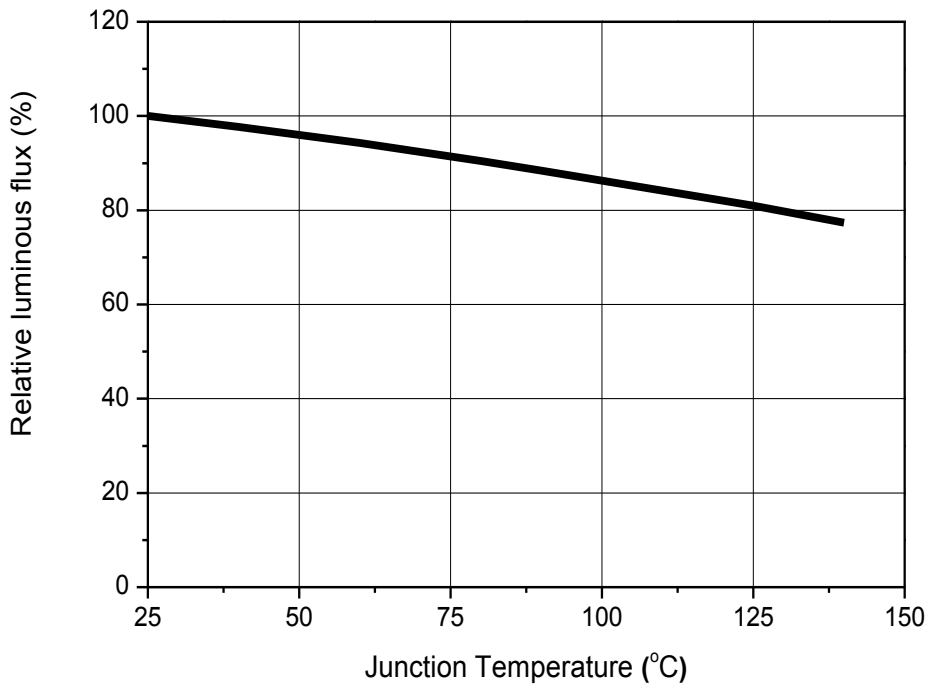
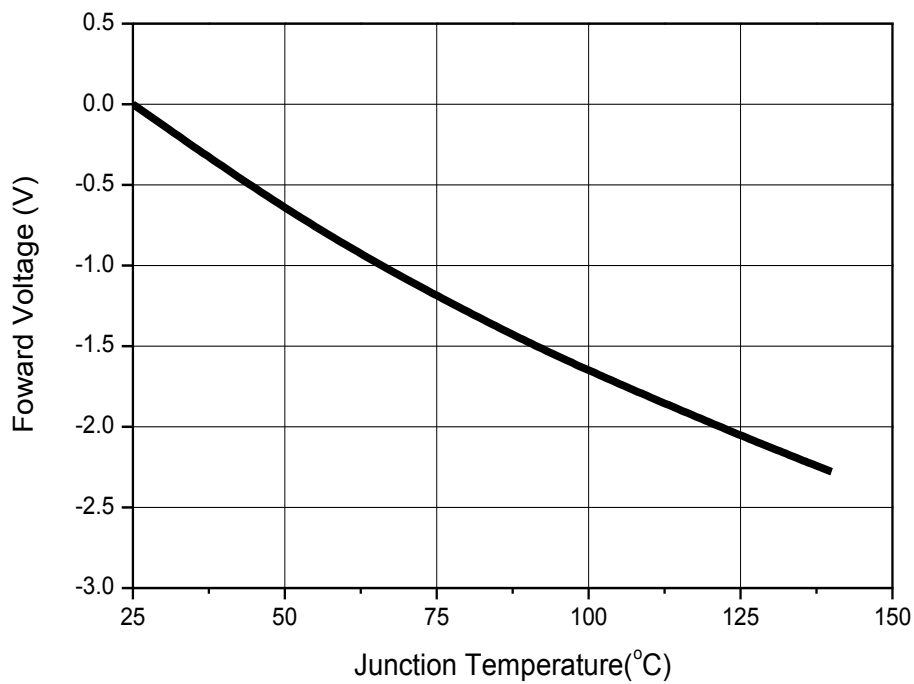
Fig 4. Radiant pattern,  $T_j=25^{\circ}\text{C}$ ,  $I_F=180\text{mA}$



## Characteristics Graph

**Fig 5. Forward Voltage vs. Forward Current,  $T_j=25^\circ\text{C}$** 

**Fig 6. Forward Current vs. Relative Luminous Flux,  $T_j=25^\circ\text{C}$** 


## Characteristics Graph

**Fig 7. Junction Temperature vs. Relative Light Output,  $I_F=180\text{mA}$** 

**Fig 8. Junction Temperature vs. Forward Voltage,  $I_F=180\text{mA}$** 


## Characteristics Graph

Fig 9. Junction Temperature vs. CIE X, Y Shift,  $I_F=180\text{mA}$  (CRI70)

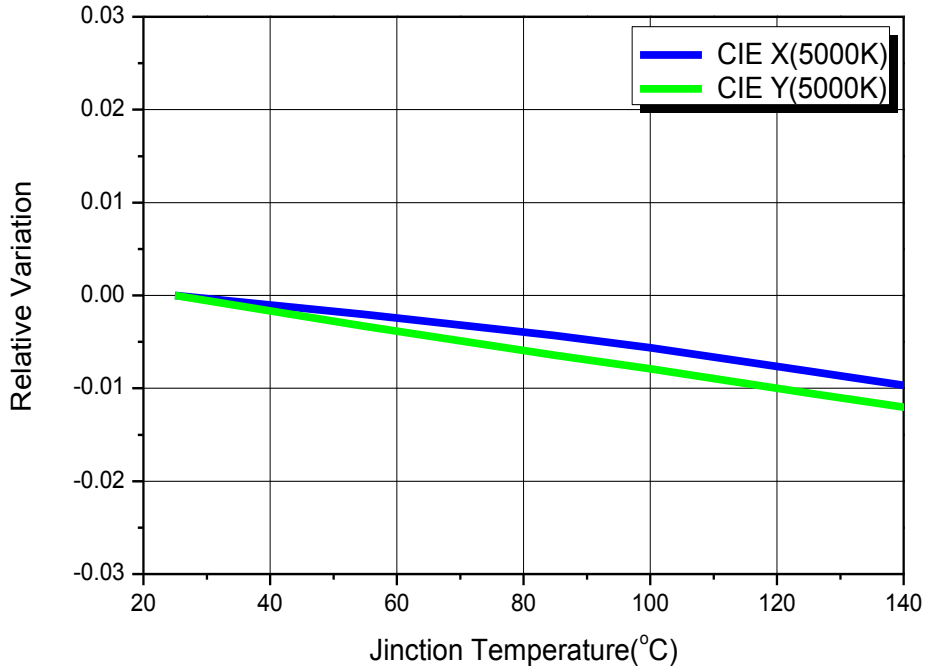
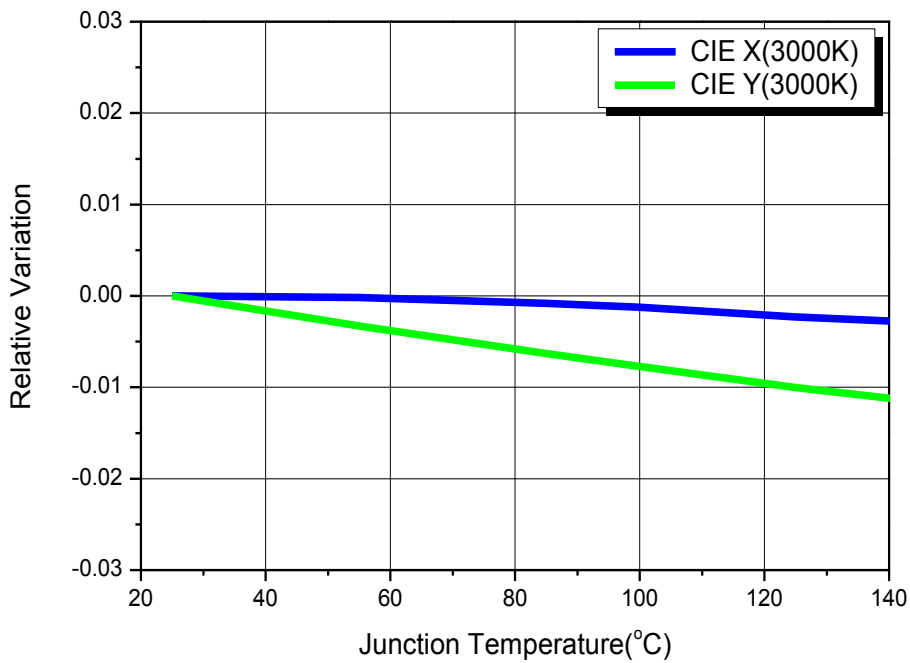
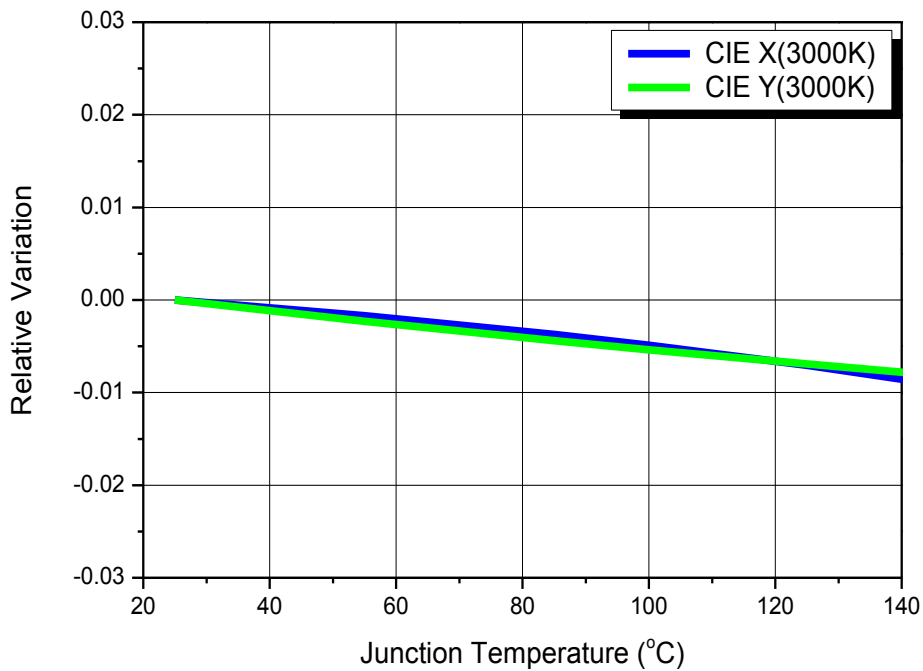
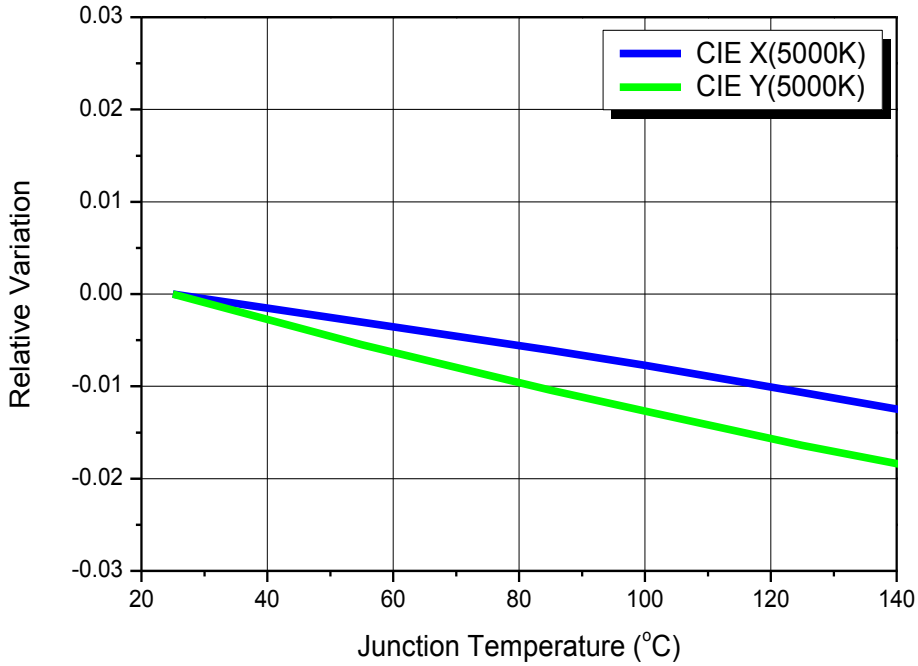


Fig 10. Junction Temperature vs. CIE X, Y Shift,  $I_F=180\text{mA}$  (CRI90)

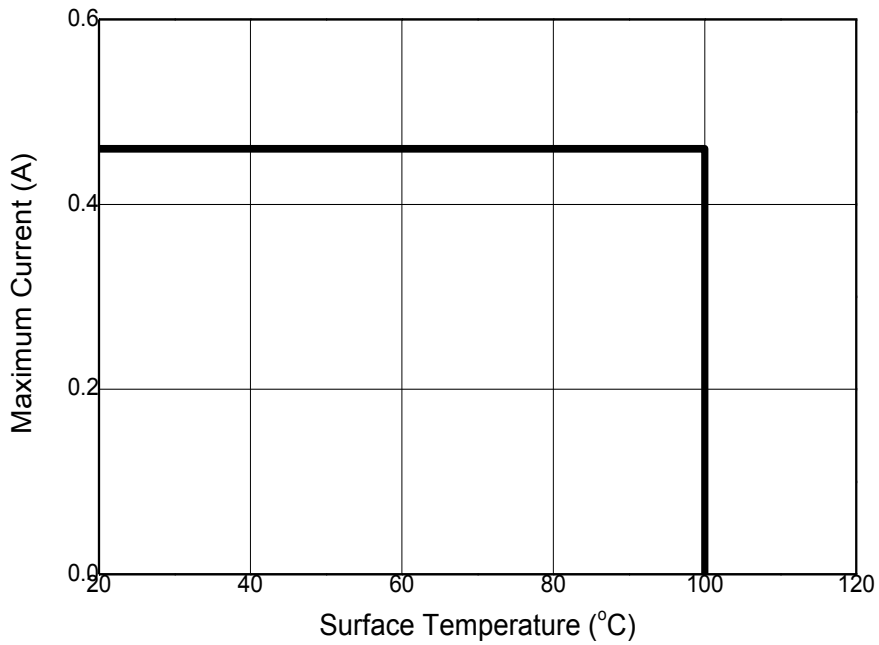


## Characteristics Graph

**Fig 11. Junction Temperature vs. CIE X, Y Shift,  $I_F=180\text{mA}$  (CRI80)**


## Characteristics Graph

Fig 12. Surface Temperature vs. Maximum Forward Current,  $T_j(\text{max.})=140^\circ\text{C}$



## Product Nomenclature

**Table 5. Part Numbering System : X<sub>1</sub>X<sub>2</sub>X<sub>3</sub> X<sub>4</sub>X<sub>5</sub> X<sub>6</sub>X<sub>7</sub> X<sub>8</sub>**

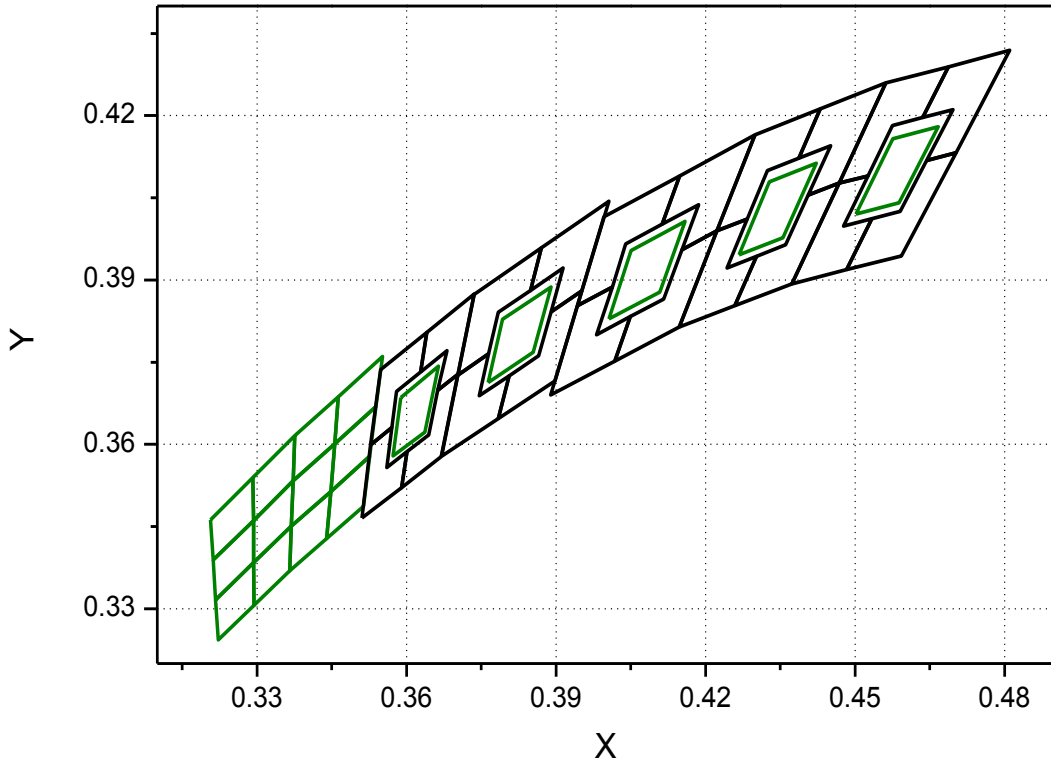
Part Number Code	Description	Part Number	Value
X <sub>1</sub>	Company	S	
X <sub>2</sub>	Package series	D	
X <sub>3</sub> X <sub>4</sub>	Color Specification	W0	CRI 70
		W8	CRI 80
		W9	CRI 90
X <sub>5</sub>	Series number	1	
X <sub>6</sub>	Lens type	F	Flat
X <sub>7</sub>	PCB type	1	PCB
X <sub>8</sub>	Revision number	C	New COB type

**Table 6. Lot Numbering System : Y<sub>1</sub>Y<sub>2</sub>Y<sub>3</sub>Y<sub>4</sub>Y<sub>5</sub>Y<sub>6</sub> – Y<sub>7</sub>Y<sub>8</sub>Y<sub>9</sub>Y<sub>10</sub> – Y<sub>11</sub>Y<sub>12</sub>Y<sub>13</sub>**

Lot Number Code	Description
Y <sub>1</sub> Y <sub>2</sub>	Year
Y <sub>3</sub> Y <sub>4</sub>	Month
Y <sub>5</sub> Y <sub>6</sub>	Day
Y <sub>7</sub> Y <sub>8</sub> Y <sub>9</sub> Y <sub>10</sub>	Mass order
Y <sub>11</sub> Y <sub>12</sub> Y <sub>13</sub>	Tray No.

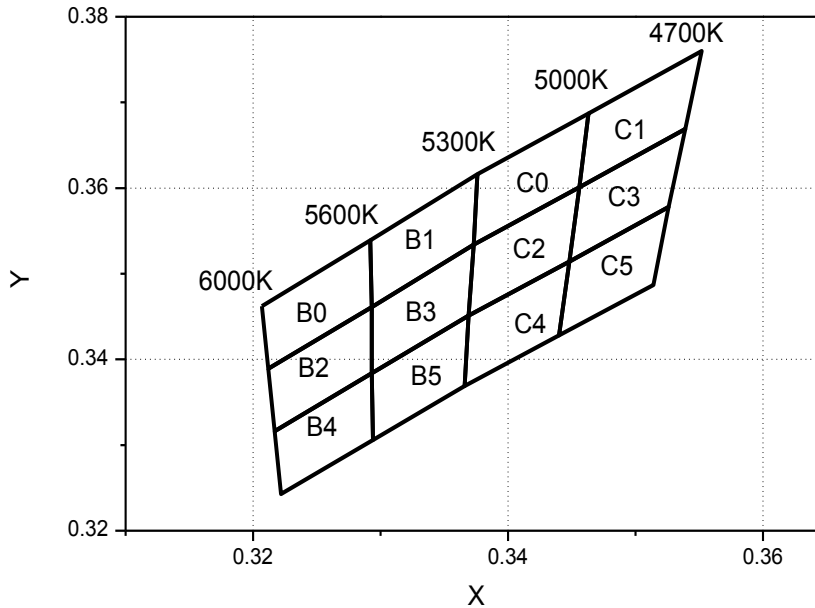
## Color Bin Structure

CIE Chromaticity Diagram



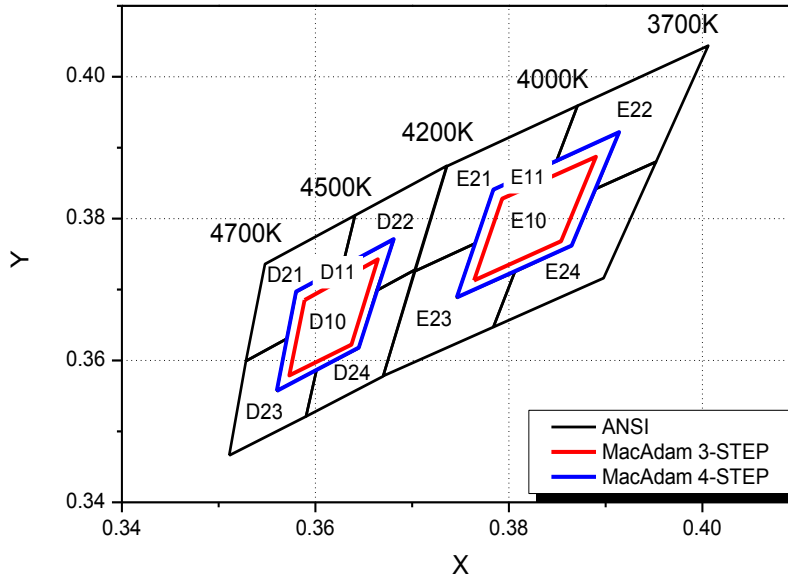


## Color Bin Structure

**CIE Chromaticity Diagram,  $T_j=25^\circ\text{C}$ ,  $I_F=180\text{mA}$** 


B0		B1		B2	
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3207	0.3462	0.3292	0.3539	0.3212	0.3389
0.3212	0.3389	0.3293	0.3461	0.3217	0.3316
0.3293	0.3461	0.3373	0.3534	0.3293	0.3384
0.3292	0.3539	0.3376	0.3616	0.3293	0.3461
B3		B4		B5	
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3293	0.3461	0.3217	0.3316	0.3293	0.3384
0.3293	0.3384	0.3222	0.3243	0.3294	0.3306
0.3369	0.3451	0.3294	0.3306	0.3366	0.3369
0.3373	0.3534	0.3293	0.3384	0.3369	0.3451
C0		C1		C2	
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3376	0.3616	0.3463	0.3687	0.3373	0.3534
0.3373	0.3534	0.3456	0.3601	0.3369	0.3451
0.3456	0.3601	0.3539	0.3669	0.3448	0.3514
0.3463	0.3687	0.3552	0.3760	0.3456	0.3601
C3		C4		C5	
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3456	0.3601	0.3369	0.3451	0.3448	0.3514
0.3448	0.3514	0.3366	0.3369	0.3440	0.3428
0.3526	0.3578	0.3440	0.3428	0.3514	0.3487
0.3539	0.3669	0.3448	0.3514	0.3526	0.3578

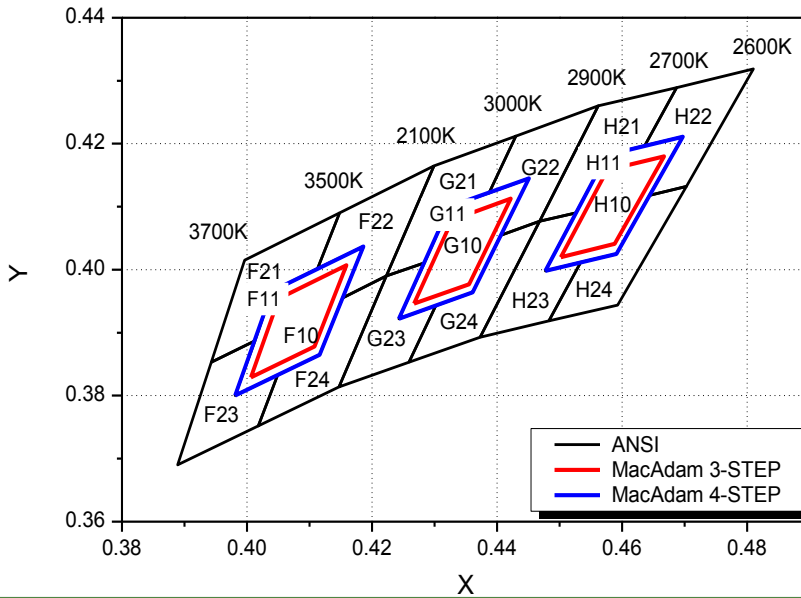
## Color Bin Structure

**CIE Chromaticity Diagram,  $T_j=25^\circ\text{C}$ ,  $I_f=180\text{mA}$** 


3-STEP				4-STEP			
D10		E10		D11		E11	
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3589	0.3685	0.3764	0.3713	0.3560	0.3557	0.3746	0.3689
0.3665	0.3742	0.3793	0.3828	0.3580	0.3697	0.3784	0.3841
0.3637	0.3622	0.3890	0.3887	0.3681	0.3771	0.3914	0.3922
0.3573	0.3579	0.3854	0.3768	0.3645	0.3618	0.3865	0.3762

ANSI							
D21		D22		D23		D24	
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3528	0.3599	0.3628	0.3732	0.3601	0.3587	0.3511	0.3466
0.3548	0.3736	0.3641	0.3805	0.3645	0.3618	0.3528	0.3599
0.3641	0.3805	0.3736	0.3874	0.3663	0.3699	0.3570	0.3631
0.3628	0.3732	0.3703	0.3728	0.3703	0.3728	0.3560	0.3558
0.3580	0.3697	0.3663	0.3699	0.3670	0.3578	0.3601	0.3587
0.3570	0.3631	0.3681	0.3771	0.3590	0.3521	0.3590	0.3521
E21		E22		E23		E24	
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.3703	0.3726	0.3890	0.3842	0.3670	0.3578	0.3784	0.3647
0.3736	0.3874	0.3914	0.3922	0.3703	0.3726	0.3806	0.3725
0.3871	0.3959	0.3849	0.3881	0.3765	0.3765	0.3865	0.3762
0.3849	0.3881	0.3871	0.3959	0.3746	0.3689	0.3890	0.3842
0.3784	0.3841	0.4006	0.4044	0.3806	0.3725	0.3952	0.3880
0.3765	0.3765	0.3952	0.3880	0.3784	0.3647	0.3898	0.3716

## Color Bin Structure

**CIE Chromaticity Diagram,  $T_j=25^\circ\text{C}$ ,  $I_f=180\text{mA}$** 


3-STEP						4-STEP					
F10		G10		H10		F11		G11		H11	
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
0.4006	0.3829	0.4267	0.3946	0.4502	0.4020	0.3981	0.3800	0.4243	0.3922	0.4477	0.3998
0.4051	0.3954	0.4328	0.4079	0.4576	0.4158	0.4040	0.3966	0.4324	0.4100	0.4575	0.4182
0.4159	0.4007	0.4422	0.4113	0.4667	0.4180	0.4186	0.4037	0.4451	0.4145	0.4697	0.4211
0.4108	0.3878	0.4355	0.3977	0.4588	0.4041	0.4116	0.3865	0.4361	0.3964	0.4591	0.4025
ANSI											
F21		F22		F23		F24					
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y				
0.4148	0.4090	0.4013	0.3887	0.4223	0.3990	0.4299	0.4165				
0.3996	0.4015	0.3943	0.3853	0.4153	0.3955	0.4148	0.4090				
0.3943	0.3853	0.3889	0.3690	0.4116	0.3865	0.4113	0.4002				
0.4013	0.3887	0.4018	0.3752	0.4049	0.3833	0.4186	0.4037				
0.4040	0.3966	0.4049	0.3833	0.4018	0.3752	0.4153	0.3955				
0.4113	0.4002	0.3981	0.3800	0.4147	0.3814	0.4223	0.3990				
G21		G22		G23		G24					
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y				
0.4223	0.3990	0.4406	0.4055	0.4147	0.3814	0.4259	0.3853				
0.4299	0.4165	0.4451	0.4145	0.4223	0.3990	0.4302	0.3943				
0.4430	0.4212	0.4387	0.4122	0.4284	0.4011	0.4361	0.3964				
0.4387	0.4122	0.4430	0.4212	0.4243	0.3922	0.4406	0.4055				
0.4324	0.4100	0.4562	0.4260	0.4302	0.3943	0.4468	0.4077				
0.4284	0.4011	0.4468	0.4077	0.4259	0.3853	0.4373	0.3893				
H21		H22		H23		H24					
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y				
0.4468	0.4077	0.4644	0.4118	0.4373	0.3893	0.4483	0.3919				
0.4562	0.4260	0.4697	0.4211	0.4468	0.4077	0.4534	0.4012				
0.4687	0.4289	0.4636	0.4197	0.4526	0.4090	0.4591	0.4025				
0.4636	0.4197	0.4687	0.4289	0.4477	0.3998	0.4644	0.4118				
0.4575	0.4182	0.4810	0.4319	0.4534	0.4012	0.4703	0.4132				
0.4526	0.4090	0.4703	0.4132	0.4483	0.3919	0.4593	0.3944				

## Color Bin Structure

**Table 7. Bin Code description**

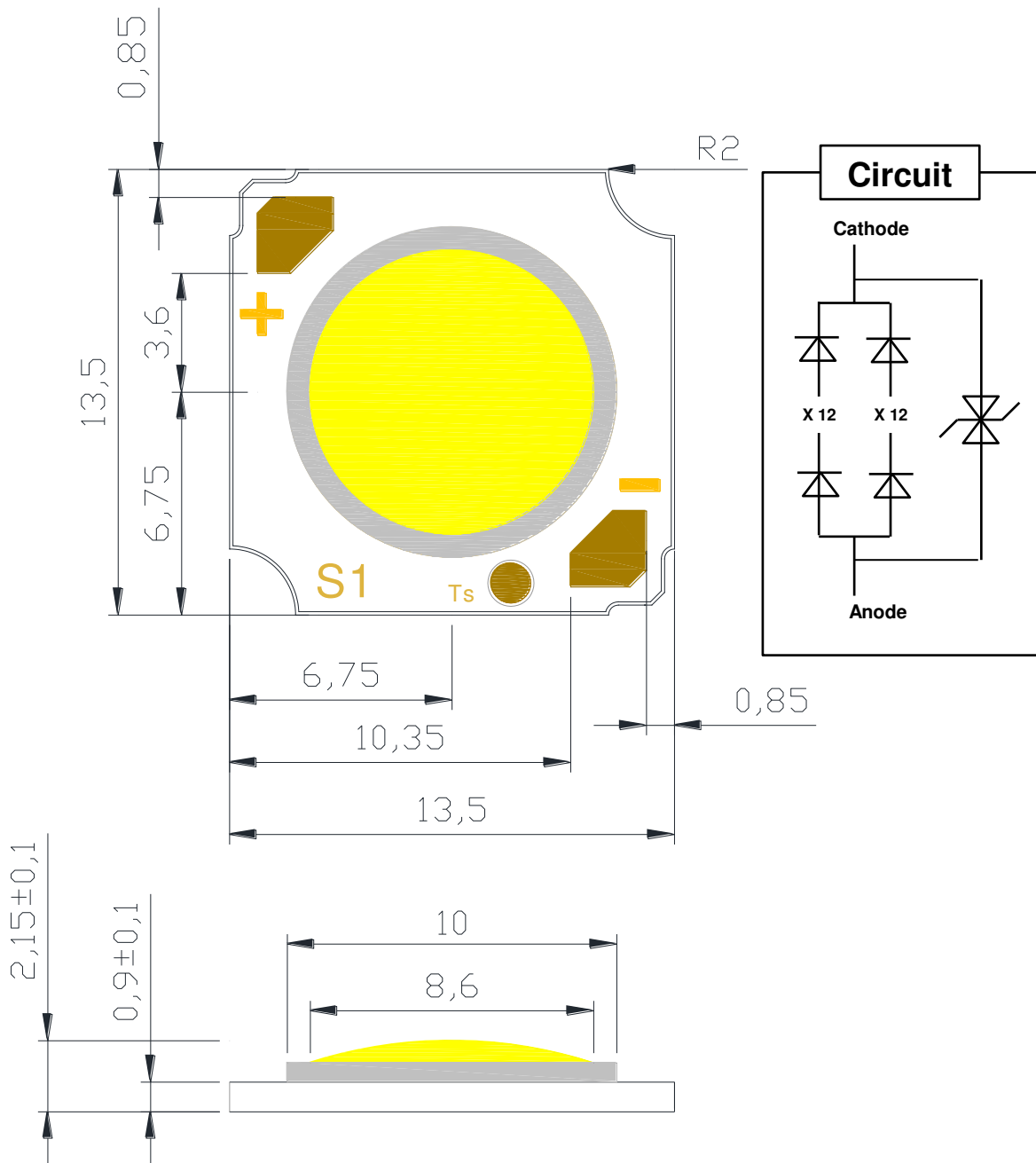
Part Number	Luminous Flux (lm) @ I <sub>F</sub> = 180mA			Color Chromaticity Coordinate @ I <sub>F</sub> = 180mA	Typical Forward Voltage (V <sub>F</sub> ) @ I <sub>F</sub> = 180mA		
	Bin Code	Min.	Max.		Bin Code	Min.	Max.
SDW01F1C	C	700	800	Refer to page.15~17	D	32.0	34.0
	D	800	900		E	34.0	38.0
	E	900	1100		F	38.0	40.0
SDW81F1C	B2	635	700	Refer to page.15~18	D	32.0	34.0
	C	700	800		E	34.0	38.0
	D	800	900		F	38.0	40.0
SDW91F1C	B1	570	635	Refer to page.15~18	D	32	34
	B2	635	700		E	34	38
	C	700	800		F	38	40

**Table 8. Ordering Information(Bin Code)**

Available ranks

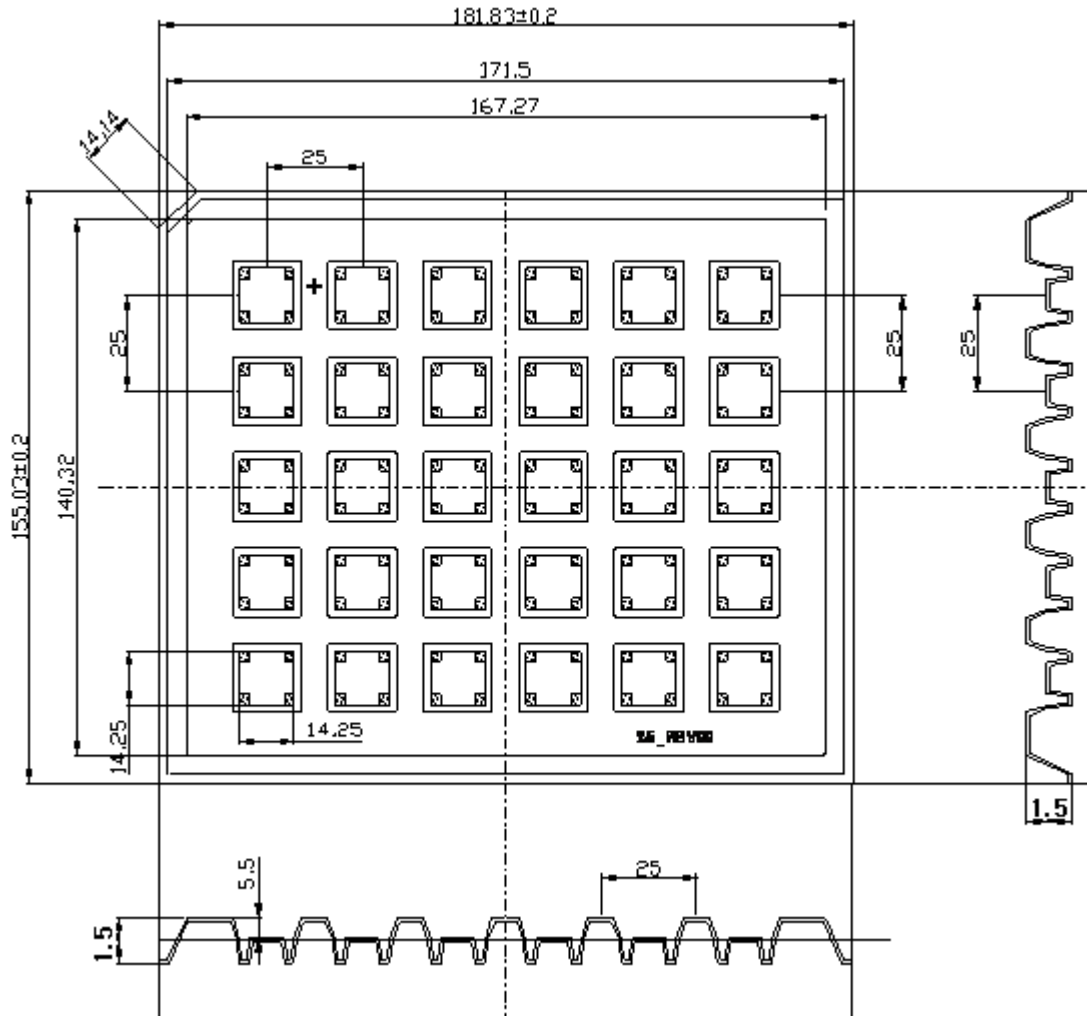
Part Number	CCT	CIE	LF rank			VF rank		
SDW01F1C	5300~6000K	B	C	D	E	D	E	F
	4700~5300K	C	C	D	E	D	E	F
	4200~4700K	D	C	D	E	D	E	F
	3700~4200K	E	C	D	E	D	E	F
SDW81F1C	5300~6000K	B	B2	C	D	D	E	F
	4700~5300K	C	B2	C	D	D	E	F
	4200~4700K	D	B2	C	D	D	E	F
	3700~4200K	E	B2	C	D	D	E	F
	3200~3700K	F	B2	C	D	D	E	F
	2900~3700K	G	B2	C	D	D	E	F
	2600~2900K	H	B2	C	D	D	E	F
SDW91F1C	3700~4200K	E	B1	B2	C	D	E	F
	3200~3700K	F	B1	B2	C	D	E	F
	2900~3200K	G	B1	B2	C	D	E	F
	2600~2900K	H	B1	B2	C	D	E	F

## Mechanical Dimensions


**Notes :**

- (1) All dimensions are in millimeters.
- (2) Scale : none
- (3) Undefined tolerance is  $\pm 0.2\text{mm}$

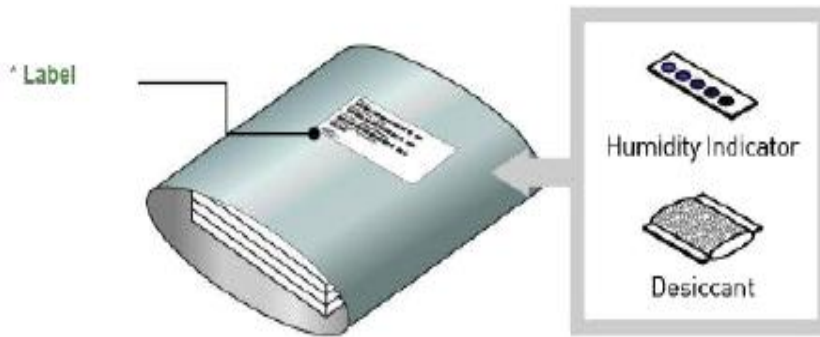
## Packaging Specification


**Notes :**

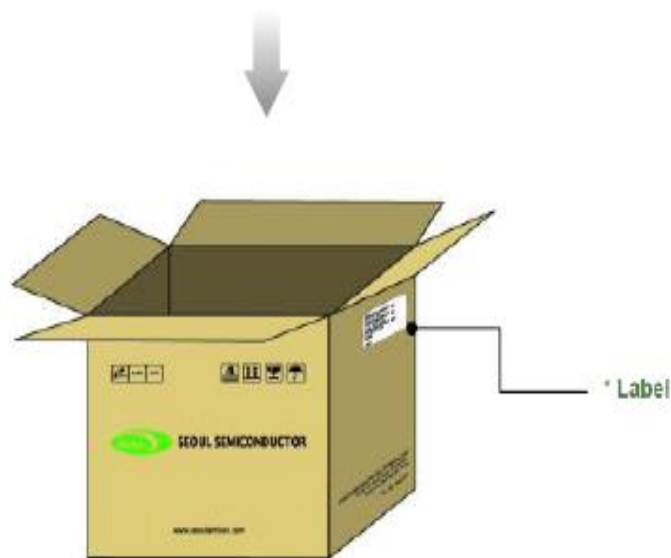
- (1) Quantity : 30pcs/Tray
- (2) All dimensions are in millimeters (tolerance :  $\pm 0.3$ )
- (3) Scale none

## Packaging Specification

### Aluminum Bag



### Outer Box



#### Notes :

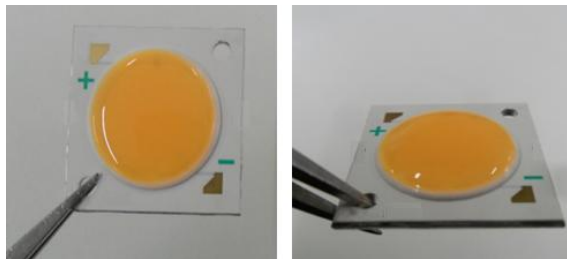
- (1) Heat Sealed after packing (Use Zipper Bag)
- (2) Quantity : 3Tray(90pcs) /Bag

## Handling of Silicone Resin for LEDs

- (1) During processing, mechanical stress on the surface should be minimized as much as possible. Sharp objects of all types should not be used to pierce the sealing compound.



- (2) In general, LEDs should only be handled from the side. By the way, this also applies to LEDs without a silicone sealant, since the surface can also become scratched.



- (3) Silicone differs from materials conventionally used for the manufacturing of LEDs. These conditions must be considered during the handling of such devices. Compared to standard encapsulants, silicone is generally softer, and the surface is more likely to attract dust. As mentioned previously, the increased sensitivity to dust requires special care during processing. In cases where a minimal level of dirt and dust particles cannot be guaranteed, a suitable cleaning solution must be applied to the surface after the soldering of wire.
- (4) Seoul Semiconductor suggests using isopropyl alcohol for cleaning. In case other solvents are used, it must be assured that these solvents do not dissolve the package or resin. Ultrasonic cleaning is not recommended. Ultrasonic cleaning may cause damage to the LED.
- (5) Please do not mold this product into another resin (epoxy, urethane, etc) and do not handle this product with acid or sulfur material in sealed space.
- (6) Avoid leaving fingerprints on silicone resin parts.



## Precaution for Use

### (1) Storage

To avoid the moisture penetration, we recommend storing Power LEDs in a dry box with a desiccant.

The recommended storage temperature range is 5°C to 30°C and a maximum humidity of 50%.

### (2) Use Precaution after Opening the Packaging. Pay attention to the following:

#### a. Recommend conditions after opening the package

- Sealing

- Temperature : 5 ~ 40°C Humidity : less than RH30%

b. If the package has been opened more than 4 week or the color of the desiccant changes.

### (3) For manual soldering

Seoul Semiconductor recommends the soldering condition

(ZC series product is not adaptable to reflow process)

#### a. Use lead-free soldering

b. Soldering should be implemented using a soldering equipment at temperature lower than 350°C.

c. Before proceeding the next step, product temperature must be stabilized at room temperature.

### (4) Components should not be mounted on warped (non coplanar) portion of PCB.

### (5) Radioactive exposure is not considered for the products listed here in.

### (6) It is dangerous to drink the liquid or inhale the gas generated by such products when chemically disposed of.

### (7) This device should not be used in any type of fluid such as water, oil, organic solvent and etc. When washing is required, IPA (Isopropyl Alcohol) should be used.

### (8) When the LEDs are in operation the maximum current should be decided after measuring the package temperature.

### (9) LEDs must be stored properly to maintain the device. If the LEDs are stored for 3 months or more after being shipped from Seoul Semiconductor, a sealed container with vacuum atmosphere should be used for storage.

### (10) The appearance and specifications of the product may be modified for improvement without notice.

## Precaution for Use

- (11) Long time exposure of sun light or occasional UV exposure will cause silicone discoloration.
- (12) Attaching LEDs, do not use adhesive that outgas organic vapor.
- (13) The driving circuit must be designed to allow forward voltage only when it is ON or OFF. If the reverse voltage is applied to LED, migration can be generated resulting in LED damage.
- (14) Please do not touch any of the circuit board, components or terminals with bare hands or metal while circuit is electrically active.
- (15) VOCs (Volatile organic compounds) emitted from materials used in the construction of fixtures can penetrate silicone encapsulants of LEDs and discolor when exposed to heat and photonic energy. The result can be a significant loss of light output from the fixture. Knowledge of the properties of the materials selected to be used in the construction of fixtures can help prevent these issues.
- (16) LEDs are sensitive to Electro-Static Discharge (ESD) and Electrical Over Stress (EOS). Below is a list of suggestions that Seoul Semiconductor purposes to minimize these effects.

### I . ESD (Electro Static Discharge)

Electrostatic discharge (ESD) is defined as the release of static electricity when two objects come into contact. While most ESD events are considered harmless, it can be an expensive problem in many industrial environments during production and storage. The damage from ESD to LEDs may cause the product to demonstrate unusual characteristics such as:

- Increase in reverse leakage current lowered turn-on voltage
- Abnormal emissions from the LED at low current

The following recommendations are suggested to help minimize the potential for an ESD event. One or more recommended work area suggestions:

- Ionizing fan setup
- ESD table/shelf mat made of conductive materials
- ESD safe storage containers

One or more personnel suggestion options:

- Antistatic wrist-strap
- Antistatic material shoes
- Antistatic clothes

Environmental controls:

- Humidity control (ESD gets worse in a dry environment)